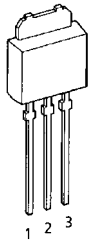
TOSHIBA Intelligent Power Device Silicon Monolithic Power MOS Integrated Circuit

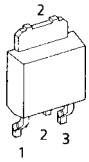
TPD1024S

Low-Side Power Switch for Motors, Solenoids, and Lamp Drivers

TPD1024S is a monolithic power IC for low-side switches. The IC has a vertical MOS FET output which can be directly driven from a CMOS or TTL logic circuit (e.g, an MPU).
The device offers intelligent self-protection function



HSIP3-P-2.30B



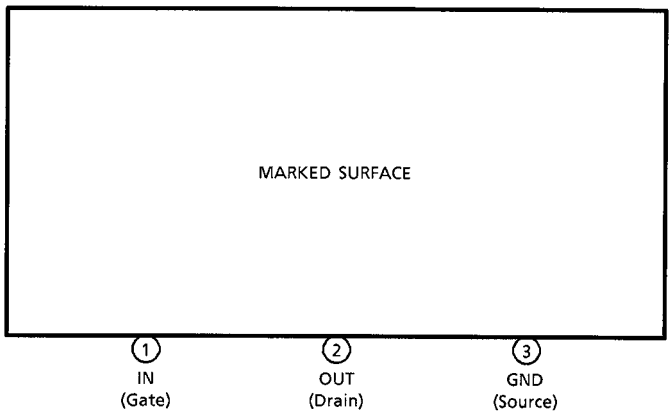
HSOP3-P-2.30A

Weight
HSIP3-P-2.30B : 0.36 g (typ.)
HSOP3-P-2.30A : 0.28 g (typ.)

Features

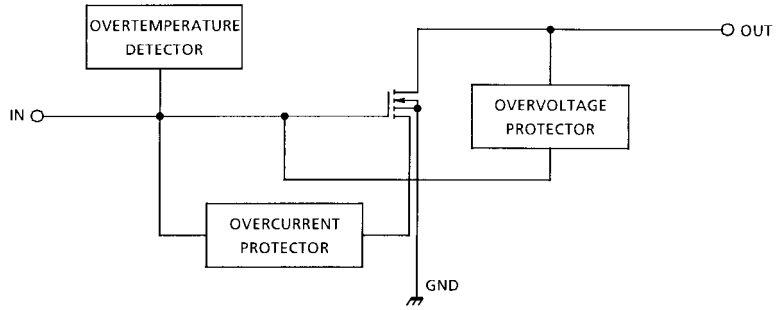
- A monolithic power IC with a new structure combining a control block and a vertical power MOS FET (π-MOS) on a single chip.
- Can directly drive a power load from a CMOS logic.
- Built-in protection against overvoltage, load short circuiting, and thermal shutdown.
- Low on resistance : $R_{DS\ (ON)}$ = 0.5 Ω(max), (@V_{IN} = 5 V, T_j = 25°C)
- 3-pin power-molded package usable for surface mounting.

Pin Assignment



Note: That because of its MOS structure, this product is sensitive to static electricity.

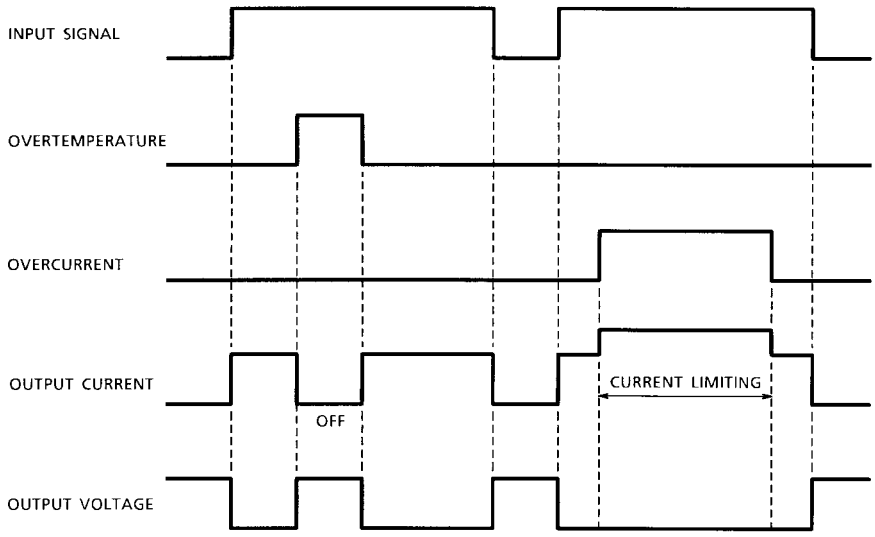
Block Diagram



Pin Description

Pin No.	Symbol	Function
1	IN	Input pin. Input is CMOS-compatible, with pull-down resistor connected. Even if the input is open, output will not accidentally turn on.
2	OUT	Output pin. When current in excess of the typical current (3.5 A (typ.)) flows to the output pin, the current limiter operates to protect the IC.
3	GND	Ground pin.

Timing Chart



Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		$V_{DS\ (DC)}$	40	V
Output current		I_D	1.5	A
Input voltage		V_{GS}	−0.5 ~ 6	V
Power dissipation	Ta = 25°C	P_D	1	W
	Tc = 25°C		10	
Operating temperature		T_{opr}	−40 ~ 85	°C
Junction temperature		T_j	150	°C
Storage temperature		T_{stg}	−55 ~ 150	°C

Recommendable Condition

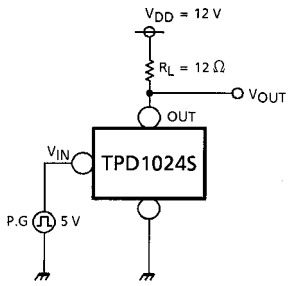
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Input voltage	V_{IN}	—	4.5	5	6	V

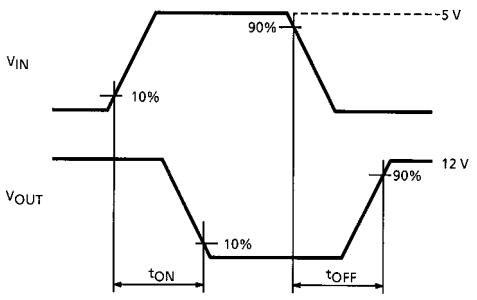
Electrical Characteristics (T_j = 25°C)

Characteristic	Symbol	Test Cir-cuit	Test Condition	Min	Typ.	Max	Unit
Drain-source breakdown voltage	$V_{(BR)\ DSS}$	—	V_{GS} = 0, I_D = 10 mA	40	—	—	V
Operating supply voltage	$V_{DD\ (OPR)}$	—	—	—	—	18	V
Current at output off	$I_{DSS\ (1)}$	—	V_{GS} = 0, V_{DS} = 40 V	—	—	3	mA
	$I_{DSS\ (2)}$	—	V_{GS} = 0, V_{DS} = 24 V	—	—	100	μA
Input threshold voltage	V_{th}	—	V_{DS} = 10 V, I_D = 1 mA	0.8	—	2.5	V
Input current	I_{GSS}	—	V_{GS} = 5 V, at normal operation	—	—	300	μA
On resistance	$R_{DS\ (ON)}$	—	V_{GS} = 5 V, I_D = 1 A	—	—	0.5	Ω
Thermal shutdown temperature	T_S	—	—	—	160	—	°C
Overcurrent protection	I_S	—	V_{DS} = 12 V, V_{GS} = 5 V	—	3.5	—	A
Switching time	t_{ON}	1	V_{DS} = 12 V, V_{GS} = 5 V, R_L = 12 Ω	—	50	—	μs
	t_{OFF}			—	10	—	μs
Diode forward voltage Between drain and source	V_{DSF}	—	I_F = 1.5 A	—	0.9	1.8	V
Avalanche energy	E_A	—	L = 10 mH, Single pulse	30	—	—	mJ

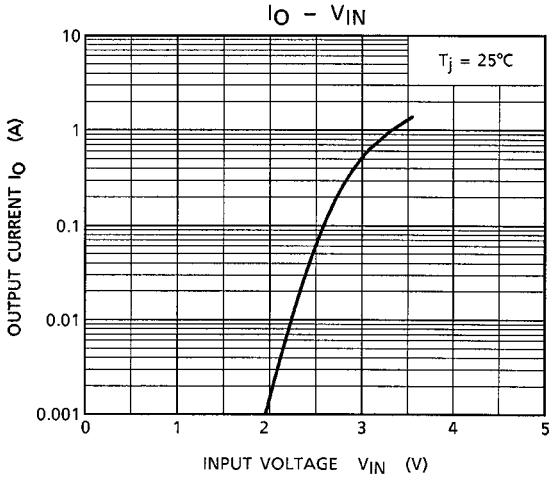
Test Circuit 1

Switching Time

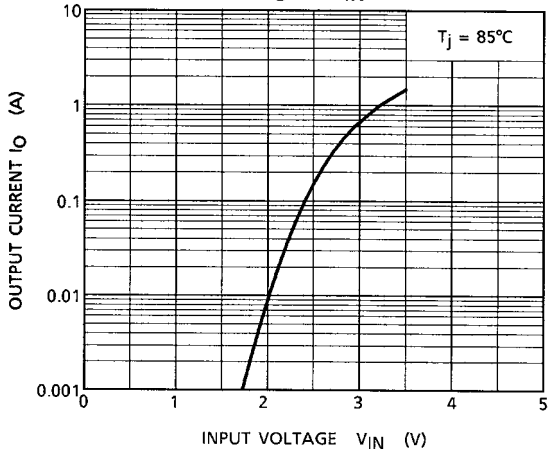




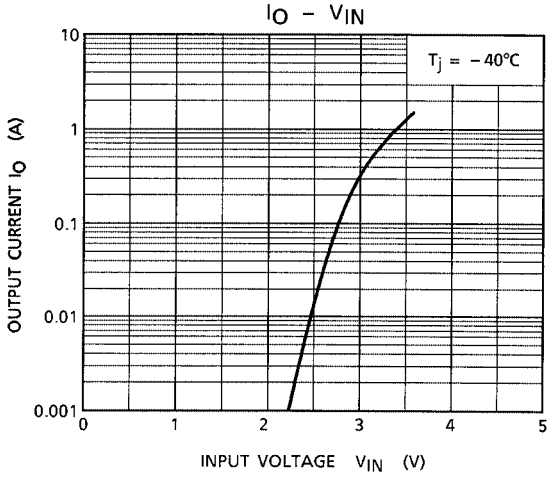
I_O – V_{IN}



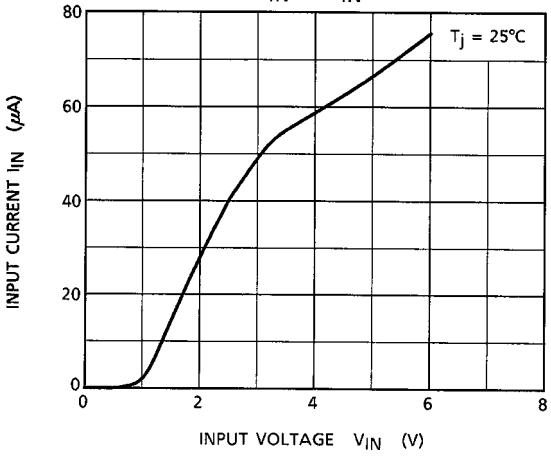
I_O – V_{IN}



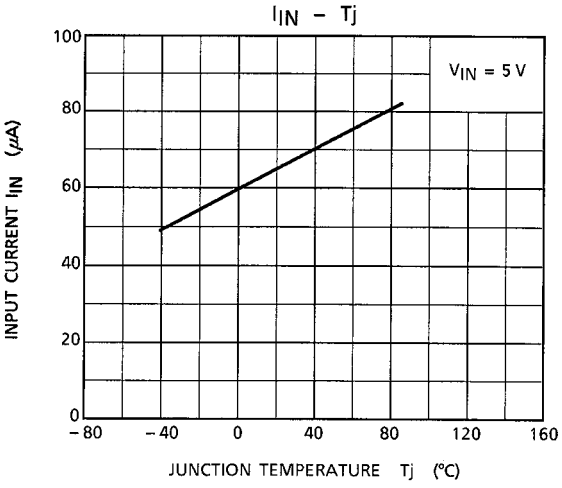
I_O – V_{IN}



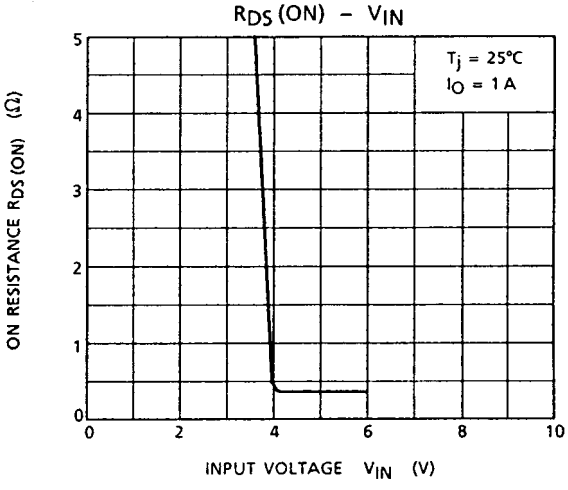
I_{IN} – V_{IN}



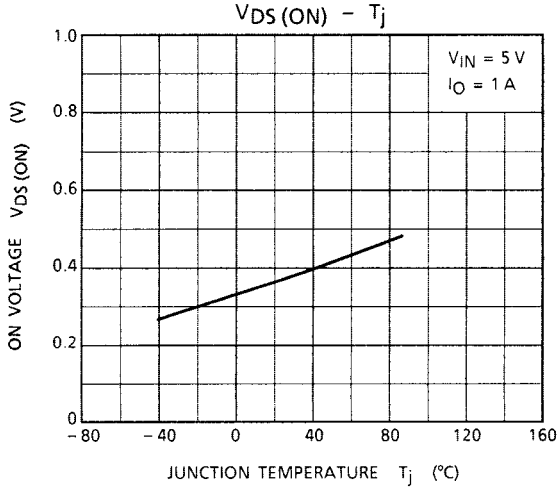
I_{IN} – T_j



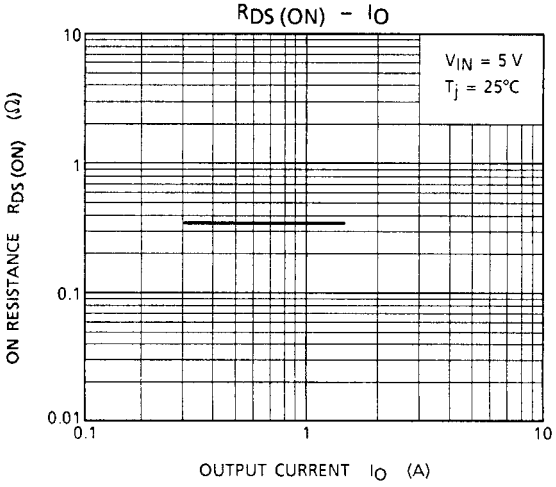
$R_{DS\,(ON)}$ – V_{IN}



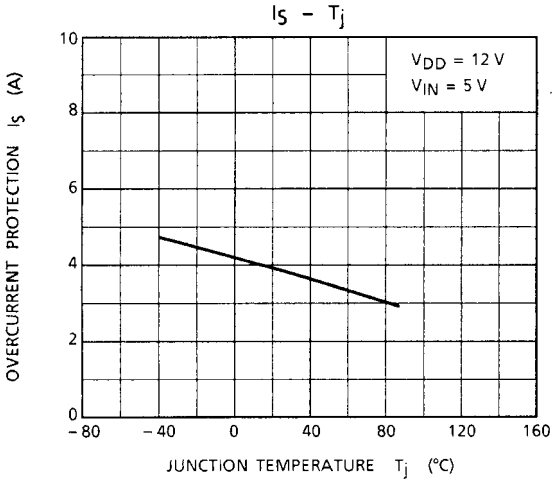
$V_{DS\,(ON)}$ – T_j



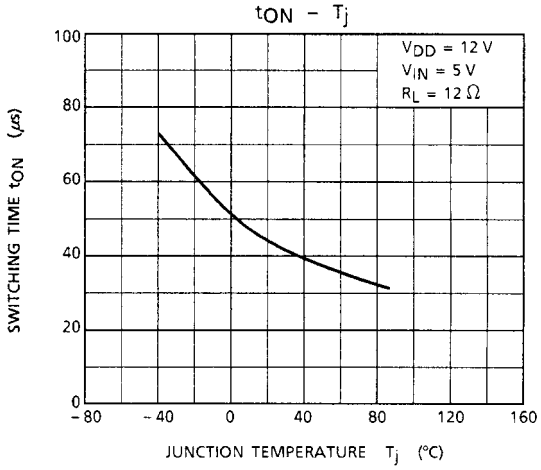
$R_{DS\,(ON)}$ – I_O



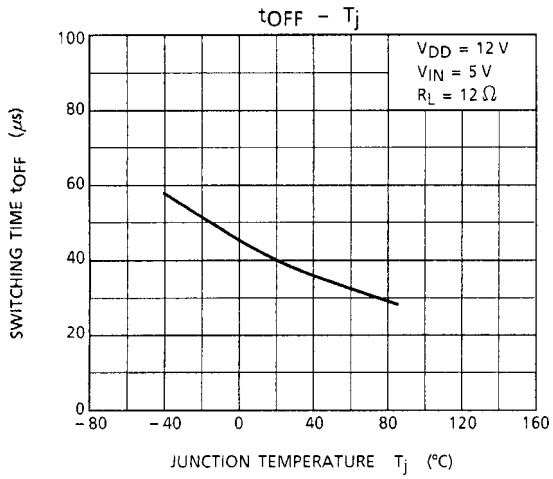
I_S – T_j



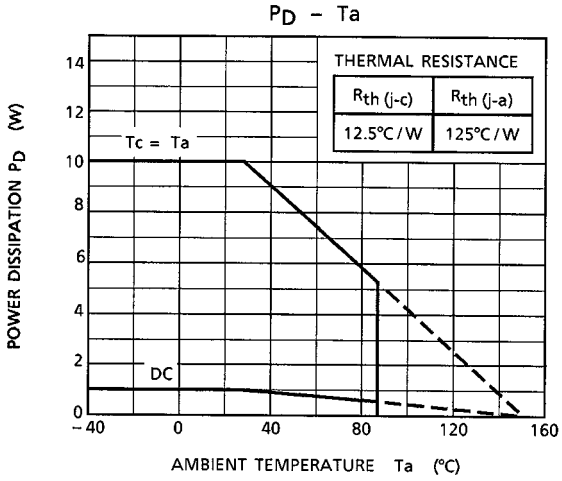
t_{ON} – T_j



t_{OFF} – T_j

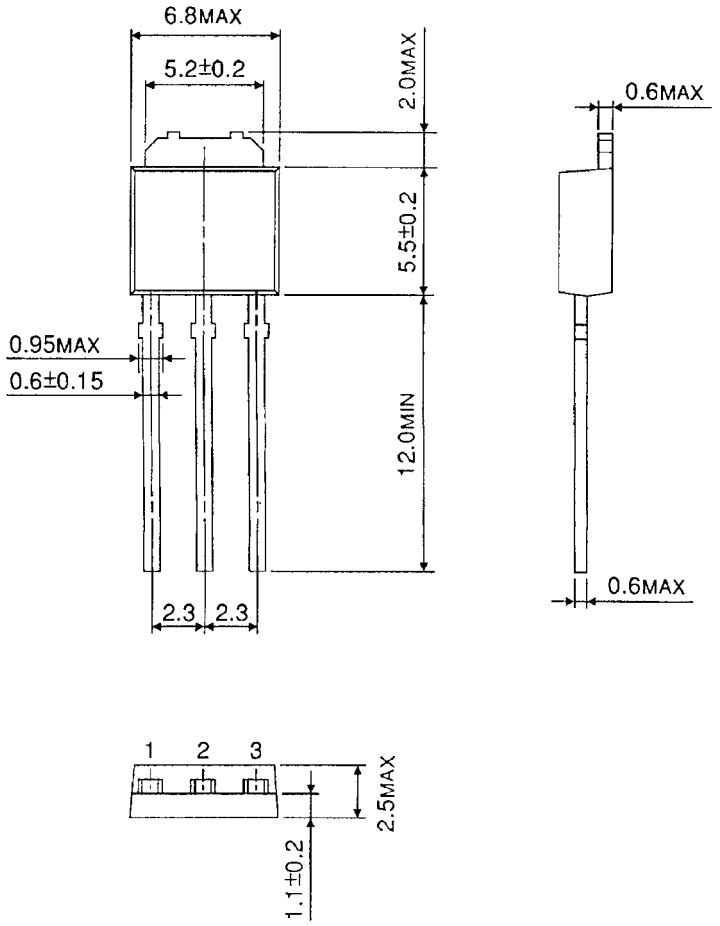


P_D – Ta



Package Dimenstions

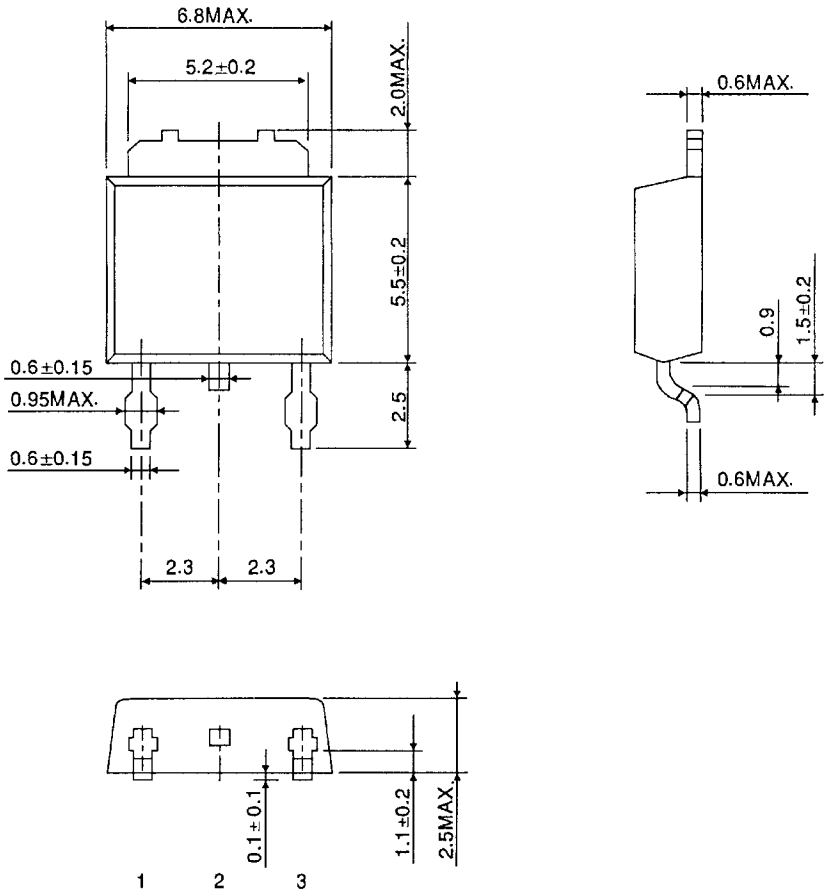
HSIP3-P-2.30B Unit : mm



Weight: 0.36 g (typ.)

Package Dimenstions

HSOP3-P-2.30A Unit : mm



Weight: 0.28 g (typ.)

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